# **ON Semiconductor**

## Is Now



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Preferred Device

# Power MOSFET 750 mAmps, 20 Volts

### N-Channel SOT-23

These miniature surface mount MOSFETs low  $R_{DS(on)}$  assure minimal power loss and conserve energy, making these devices ideal for use in space sensitive power management circuitry. Typical applications are dc–dc converters and power management in portable and battery–powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

#### **Features**

- Low R<sub>DS(on)</sub> Provides Higher Efficiency and Extends Battery Life
- Miniature SOT-23 Surface Mount Package Saves Board Space
- Pb-Free Package is Available

#### **MAXIMUM RATINGS** (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>	20	Vdc
Gate-to-Source Voltage - Continuous	V <sub>GS</sub>	± 8.0	Vdc
Drain Current - Continuous @ T <sub>A</sub> = 25°C - Pulsed Drain Current (t <sub>p</sub> ≤ 10 μs)	I <sub>D</sub>	750 2000	mA
Total Power Dissipation @ T <sub>A</sub> = 25°C	P <sub>D</sub>	400	mW
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150	°C
Thermal Resistance – Junction–to–Ambient	$R_{\theta JA}$	300	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds	$T_{\underline{b}}$	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

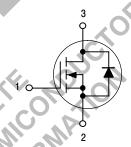


#### ON Semiconductor®

http://onsemi.com

# .750 mAMPS, 20 VOLTS $R_{DS(on)} = 85 \text{ m}\Omega$

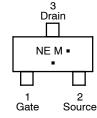
#### N-Channel



#### MARKING DIAGRAM/ PIN ASSIGNMENT



SOT-23 CASE 318 STYLE 21



NE = Specific Device Code

M = Date Code\*

= Pb-Free Package(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
MGSF1N02ELT1	SOT-23	3000/Tape & Reel
MGSF1N02ELT1G	SOT-23 Pb-Free	3000/Tape & Reel

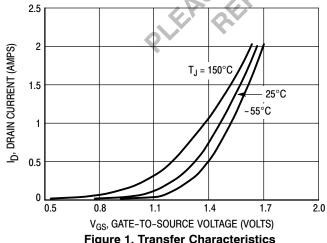
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

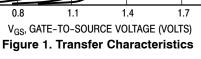
**Preferred** devices are recommended choices for future use and best overall value.

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Chara	Symbol	Min	Тур	Max	Unit		
OFF CHARACTERISTICS		1					
Drain-to-Source Breakdown Voltage (V <sub>GS</sub> = 0 Vdc, I <sub>D</sub> = 10 μA)			20	-	-	Vdc	
Zero Gate Voltage Drain Current $ (V_{DS} = 20 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}) $ $ (V_{DS} = 20 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, T_J = 125^{\circ}\text{C}) $			- -		1.0 10	μAdc	
Gate-Source Leakage Current (V <sub>GS</sub> = ± 8.0 Vdc, V <sub>DS</sub> = 0 Vdc)			_	_	±0.1	μAdc	
ON CHARACTERISTICS (Note 1)		<u> </u>					
Gate-Source Threshold Voltage (VDS	V <sub>GS(th)</sub>	0.5	-	1.0	Vdc		
Static Drain-to-Source On-Resistance $(V_{GS} = 4.5 \text{ Vdc}, I_D = 1.0 \text{ A})$ $(V_{GS} = 2.5 \text{ Vdc}, I_D = 0.75 \text{ A})$			- -	-	0.085 0.115	Ω	
DYNAMIC CHARACTERISTICS							
Input Capacitance	$(V_{DS} = 5.0 \text{ Vdc}, V_{GS} = 0 \\ V, f = 1.0 \text{ Mhz})$	C <sub>iss</sub>		160	-	pF	
Output Capacitance	$(V_{DS} = 5.0 \text{ Vdc}, V_{GS} = 0 $ V, f = 1.0 Mhz)	C <sub>oss</sub>	_	130	O <sub>2</sub>		
Transfer Capacitance	$(V_{DG} = 5.0 \text{ Vdc}, V_{GS} = 0 $ V, f = 1.0 Mhz)	C <sub>rss</sub>	-	60	_		
SWITCHING CHARACTERISTICS (Note 2)							
Turn-On Delay Time		t <sub>d(on)</sub>	-0	6.0	-	ns	
Rise Time	$(V_{DD} = 5 \text{ Vdc}, I_D = 1.0 \text{ Adc},$	tr		26	-		
Turn-Off Delay Time	$R_L = 5 \Omega, R_G = 6 \Omega$	t <sub>d(off)</sub>	· -O!	117	-		
Fall Time		tr	νΘ,	105	-		
Total Gate Charge	$(V_{DS} = 16 \text{ Vdc}, I_D = 1.2 \text{ Adc}, V_{GS} = 4.0 \text{ Vdc})$	Q <sub>T</sub>	_	6500	-	рС	
SOURCE-DRAIN DIODE CHARACTERISTICS							
Continuous Current	Is	-	-	0.6	Α		
Pulsed Current	I <sub>SM</sub>	_	-	0.75	-		
Forward Voltage (Note 2) (V <sub>GS</sub> = 0 V	V <sub>SD</sub>	-	-	1.2	V		
D. La Taul D. La Width 1800 and			l				

# TYPICAL ELECTRICAL CHARACTERISTICS





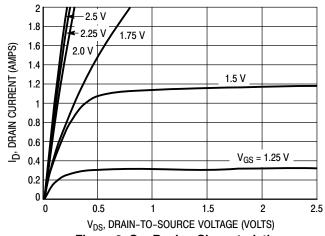
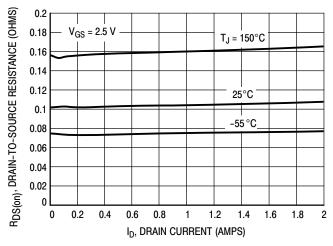


Figure 2. On-Region Characteristics

Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
 Switching characteristics are independent of operating junction temperature.

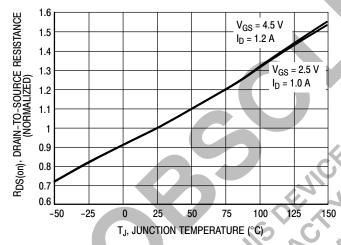
#### TYPICAL ELECTRICAL CHARACTERISTICS



RDS(on), DRAIN-TO-SOURCE RESISTANCE (OHMS) 0.14  $V_{GS} = 4.5 \text{ V}$  $T_J = 150^{\circ}C$ 0.12 0.1  $25^{\circ}\text{C}$ 0.08 -55°C 0.06 0.04 0.02 0.2 0.4 0.6 0.8 1.2 1.4 1.6 1.8 I<sub>D</sub>, DRAIN CURRENT (AMPS)

Figure 3. On-Resistance versus Drain Current

Figure 4. On-Resistance versus Drain Current



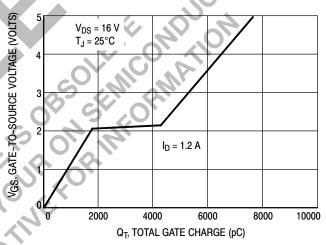
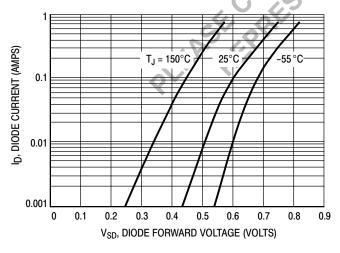


Figure 5. On-Resistance Variation Over Temperature

Figure 6. Gate Charge



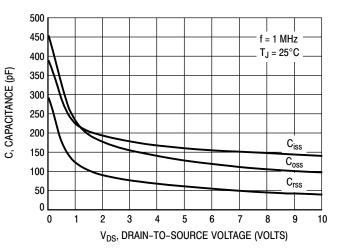
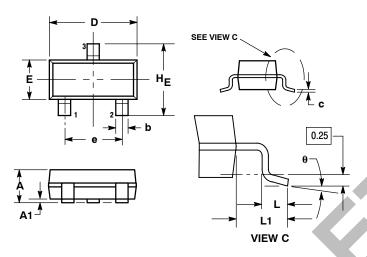


Figure 7. Body Diode Forward Voltage

Figure 8. Capacitance Variation

#### PACKAGE DIMENSIONS

#### SOT-23 (TO-236) CASE 318-08 **ISSUE AN**



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
   CONTROLLING DIMENSION: INCH.
   MAXIMUM LEAD THICKNESS INCLUDES

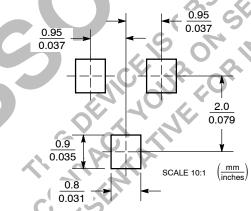
- LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

  1. 318-01 THRU -07 AND -09 OBSOLETE,
- NEW STANDARD 318-08

	MILLIMETERS			INCHES		
DIM	MIN .	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	_0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

STYLE 21: PIN 1. GATE 2. SOURCE 3. DRAIN

### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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